

1N5812/R 1N5814/R, 1N5816/R

ULTRAFAST RECOVERY RECTIFIERS

TECHNICAL DATA DATA SHEET 5546 REV A

AVAILABLE AS 1N, JAN, JANTXV JANS

Ultrafast Recovery Rectifiers

Qualified per MIL-PRF-19500/478

FEATURES / BENEFITS:

- √ Hermetic package
- ✓ All devices are 100% hot solder dipped
- ✓ JAN/ JANTX/JANTXV available per MIL-PRF-19500/478

MAXIMUM RATINGS

- ✓ Operating and Storage Temperature: -65°C to +175°C
- ✓ Thermal Resistance: 1.5 °C/W (junction to case)
- ✓ Forward surge current:400A @ 8.3 ms half-sine
- ✓ Junction Capacitance = 300pF (V_R =10V, f=1MH_z, T_J =25°C)

ELECTRICAL CHARACTERISTICS

TYPE NUMBER	WORKING PEAK REVERSE VOLTAGE \V _{RWM}	AVG RECTIFIED CURRENT Amps	MAXIMUM REVERSE CURRENT		MAX. PEAK FORWARD VOLTAGE (PULSED) 1 V _F @ 10A		MAXIMUM SURGE CURRENT ² I _{FSM}	MAXIMUM REVERSE RECOVERY TIME ³ T _{rr}
	Volts	100°C	25°C	100°C	25°C	100°C	Amps	nsec
1N5812/R 1N5814/R 1N5816/R	50 100 150	20	10	1000	0.860	0.780	400	35

Note 1: Pulse test: Pulse width 300 µsec, duty cycle 2%

Note 2: $t_p = 8.3$ ms surge, $T_c = 100$ °C Note 3: $I_F = I_R = 1$ A, $I_{(REC)} = 0.1$ A

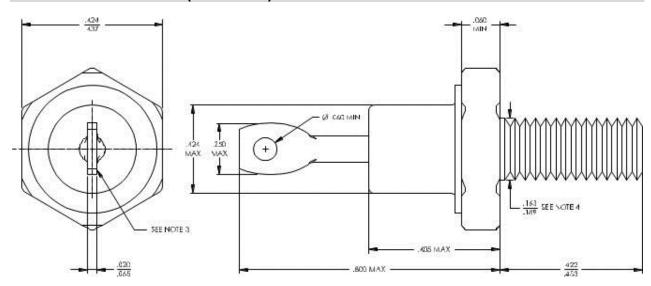


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PACKAGE DIMENSIONS (inches/mm)



NOTES:

- 1. Dimensions are in inches.
- 2. Millimeters are given for general information only.
- 3. Angular orientation of this terminal is undefined. Square or radius on end of terminals is optional.
- 4. Diameter variations within these limits are permitted.
- 5. The ANSI thread reference is 0.190-32 UNF-2A.
- 6. Max pitch diameter of plated threads shall be basic pitch diameter 0.169 inch (4.29 mm) reference FED-STD-H28 (Screw Thread Standards for Federal Services.)
- 7. Units must not be damaged by torque of 15 inch-pounds applied to 0.190-32 UNF-2B nut assembled on thread
- 8. Complete threads to extend to within 0.078 inch (1.98 mm) of the seating plane.
- 9. Terminal-end shape is unrestricted.

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